



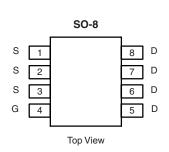
## N-Channel 150-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
150	0.050 at V <sub>GS</sub> = 10 V	5.0		

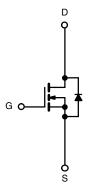
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si4488DY-T1-E3 (Lead (Pb)-free) Si4488DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise n	oted		_
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	150		V
Gate-Source Voltage		$V_{GS}$	± 20		V
Opation	T <sub>A</sub> = 25 °C	1	5.0	3.5	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C	- I <sub>D</sub>	4.0	2.8	
Pulsed Drain Current		I <sub>DM</sub>	50		Α
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	25		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.8	1.4	
W	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.1	1.56	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	T FD	2.0	1.0	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifestor Location to Australia	t ≤ 10 s	R <sub>thJA</sub>	33	40	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	' 'thJA	65	80	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	$R_{thJF}$	17	21	

a. Surface Mounted on 1" x 1" FR4 board.

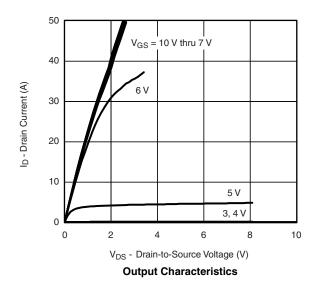
## Vishay Siliconix

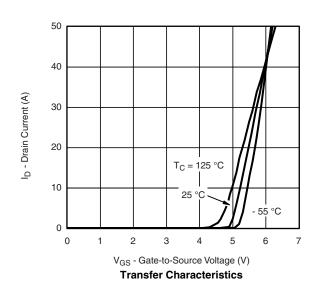


<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V$ , $V_{GS} = \pm 20 V$			± 100	nA	
Zava Cata Valtaga Drain Current	1	V <sub>DS</sub> = 120 V, V <sub>GS</sub> = 0 V			1		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A		0.041	0.050	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 5 A		18		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 2.8 A, V <sub>GS</sub> = 0 V		0.75	1.1	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			30	36		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 75 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 5 \text{ A}$		8.5		nC	
Gate-Drain Charge	$Q_{gd}$			8.5			
Gate Resistance	$R_g$		0.2	0.85	1.2	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			12	18		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 75 V, $R_L$ = 15 $\Omega$		7	11		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D} \cong \text{5 A, V}_\text{GEN} = \text{10 V, R}_\text{g} = \text{6} \ \Omega$		22	33	ns	
Fall Time	t <sub>f</sub>			10	15		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.8 A, dI/dt = 100 A/μs		40	70		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



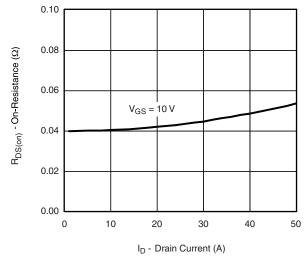


Notes: a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

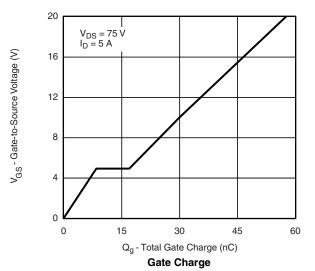


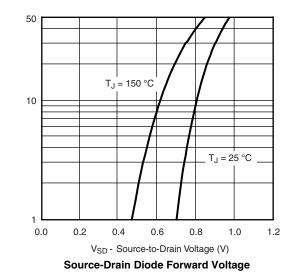


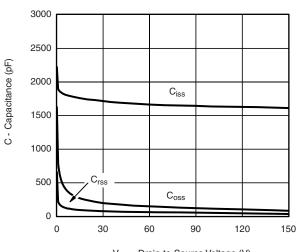
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#### On-Resistance vs. Drain Current

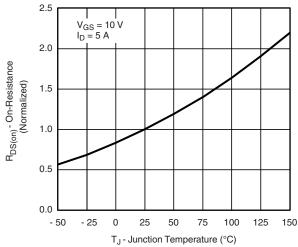




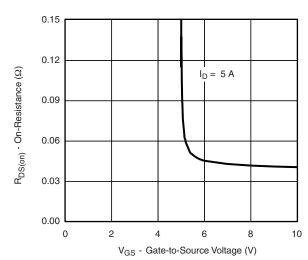


V<sub>DS</sub> - Drain-to-Source Voltage (V)





#### On-Resistance vs. Junction Temperature



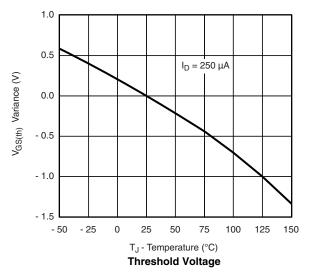
On-Resistance vs. Gate-to-Source Voltage

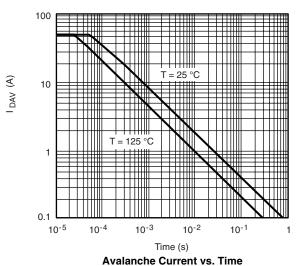
I<sub>S</sub> - Source Current (A)

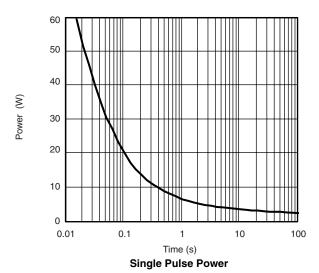
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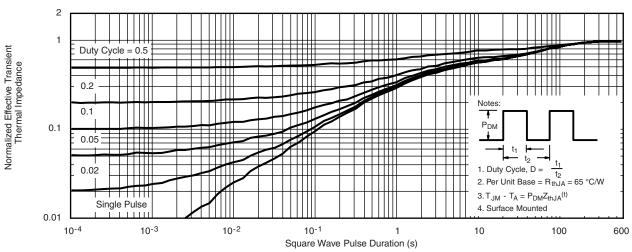
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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





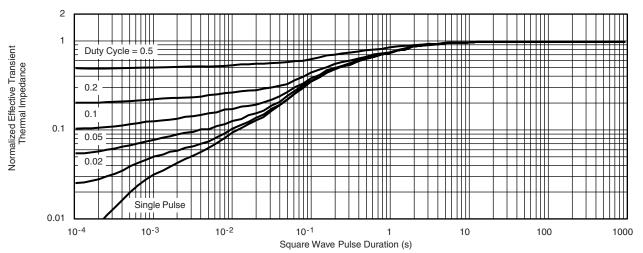




Normalized Thermal Transient Impedance, Junction-to-Ambient



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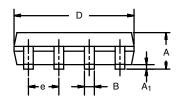
Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?71240">www.vishay.com/ppg?71240</a>.



**SOIC (NARROW): 8-LEAD** JEDEC Part Number: MS-012







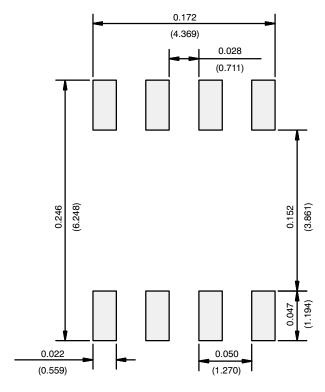
	MILLIM	IETERS	INCHES		
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
Е	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I. 11-Sep-06					

DWG: 5498

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## **RECOMMENDED MINIMUM PADS FOR SO-8**



Recommended Minimum Pads Dimensions in Inches/(mm)

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